## **Bipolar Transistor**

### **Description:**

This is a silicon NPN transistor in a TO-18 type case designed primarily for amplifier and switching applications. The device features high breakdown voltage, Low leakage current, low capacity, and beta useful over an extremely wide current range.

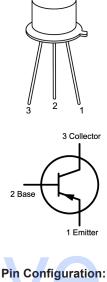
**Maximum Ratings:** 

Characteristic	Symbol	Rating	Unit
Collector-Base Voltage	V <sub>CBO</sub>	140	
Collector-Emitter Voltage	V <sub>CEO</sub>	80	V
Emitter Base Voltage	V <sub>EBO</sub>		
Continuous Collector Current	I <sub>C</sub>	1	A
Total Device Dissipation -(T <sub>A</sub> = +25°C), Derate Above 25°C	P	0.5 2.85	w
Total Device Dissipation -(T <sub>A</sub> = +25°C), Derate Above 25°C	P <sub>D</sub>	1.8 10.6	mW/°C
Operating Junction Temperature Range	TJ	05 to 1000	°C
Storage Temperature Range,	T <sub>stg</sub>	-65 to +200	C
Thermal Resistance, Junction-to-Case	R <sub>thJC</sub>	97	°C/W
Thermal Resistance, Junction-to-Ambient	R <sub>thJA</sub>	350	C/VV
Lead Temperature (During Soldering, 1/16" from case, 60sec max)	TL	300	°C

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NPN





2. Base

3. Collector



29/04/13 V1.0







#### **Electrical Characteristics:** (TA = +25°C Unless otherwise specified)

Parameter	Symbol Test Conditions		Min.	Max.	Unit
Collector-Emitter Breakdown Voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> = 30mA, I <sub>B</sub> = 0	80		
Collector-Base Breakdown Voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 100μΑ. I <sub>E</sub> = 0	140	-	V
Emitter-Base Breakdown Voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> = 100μΑ. I <sub>C</sub> = 0	7		
Collector Cut-Off Current		V <sub>CB</sub> = 90V, I <sub>E</sub> = 0		0.01	
Collector Cut-On Cutrent	СВО	V <sub>CB</sub> = 90V, I <sub>E</sub> = 0, T <sub>A</sub> = +150°C	-	10	μA
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>BE</sub> = 5V, Ic = 0		0.01	А

#### **ON Characteristics**

		V <sub>CE</sub> = 10V, I <sub>C</sub> = 0.1mA	50		
	h <sub>FE</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 10mA	90	-	
DC Current Gain (Note 1)		V <sub>CE</sub> = 10V, I <sub>C</sub> = 150mA	100	300	
		V <sub>CE</sub> = 10V, I <sub>C</sub> = 150mA, TA = -55°C	40		-
		V <sub>CE</sub> = 10V, I <sub>C</sub> = 500mA	50	-	
		V <sub>CE</sub> = 10V, I <sub>C</sub> = 1A	15		
Collector Emitter Seturation Voltage	V	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA		0.2	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> = 500mA, I <sub>B</sub> = 50mA	-	0.5	V
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> = 150mA, I <sub>B</sub> = 15mA		1.1	

#### **Small - Signal Characteristics**

Current Gain-Bandwidth Product	f <sub>T</sub>	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 20MHz	100	400	MHz
Output Capacitance	C <sub>obo</sub>	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1MHz	1Hz 12		рF
Input Capacitance	$C_{lbo}$ $V_{BE} = 500 \text{mV}, l_{C} = 0, f = 1 \text{MHz}$		60	рг	
Small-Signal Current Gain	h <sub>fe</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 1mA, f = 1kHz	80	400	-
Collector-Base Time Constant	rb'C <sub>c</sub>	V <sub>CB</sub> = 10V, I <sub>E</sub> = 10mA, f = 79.8MHz		400	ps
Noise Figure	NF	$V_{CE}$ = 10V, I <sub>C</sub> - 100µA. f = 1kHz, R <sub>S</sub> = 1kΩ	-	4	dB

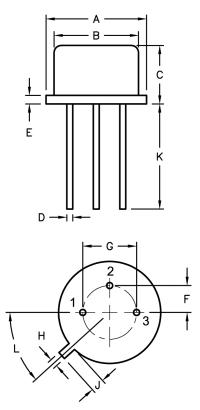
#### Note:

1. Pulse Test : Pulse Width  $\leq$ 300µs, Duty Cycle  $\leq$ 2%

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**Pin Configuration:** 

- 1. Emitter
- 2. Base
- 3. Collector

Dim	Α	В	С	D	E	F	G	Н	J	К	L
Min.	5.24	4.52	4.31	0.4	-	-	-	0.91	0.71	12.7	45°
Max.	5.84	4.97	5.33	0.53	0.76	1.27	2.97	1.17	1.21	-	40

**Dimensions : Millimetres** 

#### Part Number Table

Description	Part Number		
Transistor, NPN, 1A, 80V, TO-18	2N3700		

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